NSN 5961-00-791-3730 Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
0.260 inches
Terminal Length:
0.175 inches
Overall Height:
0.050 inches
Overall Width:
0.150 inches
Electrode Internally-electrically Connected To Case:
Collector
Component Name And Quantity:
8 semiconductor device diode
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon all semiconductor device diode
Voltage Rating In Volts Per Characteristic:
60.0 reverse voltage, instantaneous all semiconductor device diode
Power Rating Per Characteristic:
500.0 milliwatts small-signal input power, common-collector preset all semiconductor device diode
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air
Special Features:
All semiconductor device diode junction pattern arrangement: pn
Terminal Type And Quantity:
10 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0